## Theory of phonon-induced spin relaxation in laterally coupled quantum dots

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Phonon-induced spin relaxation in coupled lateral quantum dots in the presence of spin-orbit coupling is calculated. The calculation for single dots is consistent with experiment. Spin relaxation in double dots at useful interdot couplings is dominated by spin hot spots that are strongly anisotropic. Spin hot spots are inelective for a diagonal crystallographic orientation of the dots with a transverse in-plane eld. This geometry is proposed for spin-based quantum information processing.

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Understanding spin relaxation in coupled quantum dots is important for setting the eciency of spin-based applications of information processing, such as spin quantum computing [1] or controlled generation of spin entanglement [2]. Phonon-induced spin relaxation has already been studied theoretically in single dots for electrons [3, 4, 5, 6, 7, 8, 9, 10, 11, 12], holes [13], and excitons [14], and in one-dimensional coupled dots [15]. Recently, spin relaxation of electrons in single dots has been measured [16].

Here we present a realistic calculation of phonon induced spin relaxation in single and coupled lateral quantum dots form ed over a depleted two dim ensional electron gas in GaAs grown along [001], the most typical growth direction. We show that our calculation is consistent with the single-dot experim ent [16]. We predict that: (i) Spin relaxation in coupled dots is strongly anisotropic with respect to the orientation of both an in-plane magnetic eld (due to the interplay of the Bychkov-Rashba and D resselhaus spin-orbit term s) and the dots' axis. The anisotropy is limited by the in-plane inversion symmetry only. (ii) The spin relaxation rate varies strongly with the inter-dot coupling, having a giant enhancem ent at a signi cant range of useful tunneling am plitudes due to spin hot spots (anticrossings caused by spin-orbit coupling [9, 17, 18, 19]). This variation, which is over several (four to ve) orders of magnitude, should be included in any realistic modeling of spin coherence phenomena in coupled quantum dots with controlled temporal evolution of the coupling. (iii) Fortunately, the e ects of (ii) are absent at speci c con gurations. The most robust (with respect to materials parameters) such a conguration is with dots oriented along [110] (or [110]) with the in-plane magnetic eld along [110] ([110]). We propose to use this con guration for spin-based quantum inform ation experim ents.

Our single-electron H am iltonian is H = T + V + H  $_{\rm SO}$  + H  $_{\rm Z}$ . Here T is the operator of the kinetic energy with the magnetic eld B introduced by minimum coupling, and V is the double-dot con nement potential,

$$V(r) = (1=2)m!_0^2 m \inf(r d)^2; (r+d)^2 g:$$
 (1)

The plane radius vector is r = (x;y), where x = [100]

and y = [010] are the crystallographic axes, while d denes the distance (as well as tunneling energy at B = 0) and the orientation of the dots; the angle between d and  $\hat{x}$  is denoted below as . The conduction electron mass is m and the single-dot (d = 0) con ning energy is h!<sub>0</sub>. The spin-orbit coupling comprises three contributions [20]: H<sub>SO</sub> = H<sub>BR</sub> + H<sub>D</sub> + H<sub>D3</sub>, where

$$H_{BR} = _{BR} (_{x}K_{y} _{y}K_{x});$$
 (2)

$$H_{D} = {}_{c}hK^{2}_{z}i(_{x}K_{x} + _{y}K_{y});$$
 (3)

$$H_{D3} = (_{c}=2) _{x}K_{x}K_{y}^{2} _{y}K_{y}K_{x}^{2} + hx;$$
 (4)

are the Bychkov-Rashba, linear D resselhaus, and cubic D resselhaus couplings. K inem atic wave vector operators are K = ir + (e=h)A, where A is the vector potential to B. While both  $_{\rm B\,R}$  and the quantum average,  $h\hat{K}_{\rm z}^{\,2}i$ , in the growth direction 2, are tunable by a top gate,  $_{\rm C}$  is a band parameter. Below we use  $l_{\rm B\,R}=h^2=2m_{\rm B\,R}$  and  $l_{\rm D}=h^2=2m_{\rm C}h\hat{K}_{\rm z}^{\,2}i$  as elective spin-orbit lengths. The last term in the H am iltonian is the Zeem an splitting H  $_{\rm Z}=$  (g=2)  $_{\rm B}$  B, expressed by the band g-factor g and the Bohr magneton  $_{\rm B}$ .

Single electron states are obtained by num erically diagonalizing Hamiltonian Husing the Lanczos algorithm. The GaAsm aterials parameters are used:  $m = 0.067m_e$ (m  $_{\rm e}$  is the free electron m ass), g = 0.44, and  $_{\rm c} = 27.5$ eV A 3 [20]. The linear D resselhaus coupling is chosen to be  $_{c}hK_{z}^{2}i = 4:5 \text{ m eV A}$ , corresponding to a 11 nm wide ground state of a triangular con ning potential [21]. The Bychkov-Rashba parameter  $_{\rm B\,R}$  is 3.3 m eV A, in line with experiments [22, 23]. The above  $_{\rm c}hK_{\rm z}^{\rm 2}i$  and  $_{\rm B\,R}$ are selected to be both generic and consistent with the experim ent of Ref. [16] (see Fig. 1). Our con ning energy h! o is 1:1 m eV, corresponding to the con ning length of  $l_0 = 32 \text{ nm}$ , describing the experim ental system of Ref. [16]. Finally, the magnetic vector potential is given in Landau's gauge,  $A = (B_? = 2)(y;x;0)$  for the case of a perpendicular magnetic eld  $B = B_2 \hat{z}$ ; if the eld is in plane, B =  $B_{jj}(\cos j\sin j\theta)$ , where is the angle between the eld and x, cyclotron e ects are neglected. This is justifed here for elds up to about 10 T, for which the magnetic length is greater than the con ning length in the z-direction.

W hile spin-orbit terms couple opposite spin states,

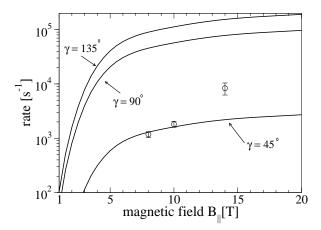


FIG.1: Calculated spin relaxation rate for a single quantum dot as a function of B  $_{\rm jj}$  applied along [110], [010], and [110]. The sym bols are experim ental data from R ef. 16. The calculated curves for B  $_{\rm jj}$  > 10 T are not realistic since they do not incorporate cyclotron e ects in the z direction.

electron-phonon coupling enables transitions between such states. Here we include the most relevant term s deform ation and piezoelectric acoustic electron-phonon potentials (direct spin-dependent electron-phonon couplings appear ine cient [3, 4]),

The sum m ation is overphonon wave vectors  $\mathbb{Q}=(q;\mathbb{Q}_z)$  and polarizations (two acoustic, t, and one longitudinal, l). The phonon creation and annihilation operators are denoted by  $b^y$  and b, respectively. For G aAs the m ass density is = 5:3  $10^3~\text{kg/m}^3$ , the phonon velocities are  $c_1=5:3$   $10^3~\text{m/s}$  and  $c_t=2:5$   $10^3~\text{m/s}$ , the deform ation potential  $_e=7:0~\text{eV}$ , and the piezoelectric constant  $eh_{14}=1:4$   $10^9~\text{eV/m}$ ; V is the unit cell volume e and N is the number of unit cells. The geometric factors M depend only on the direction of Q [24].

We calculate the rate of spin relaxation as the transition probability (given by the Ferm i golden rule) due to H  $_{\rm ep}$ , from the upper Zeem an split ground state (denoted as  $_{\rm S}^{\#}$  in [19]) to all lower states (which have necessarily opposite spin). If the Zeem an splitting is smaller than the orbital excitation energy, the spin relaxes to the ground state ( $_{\rm S}^{"}$ ) only. If, however, more orbital states are present below the upper Zeem an split state, transitions to all lower states contribute to spin relaxation. This is particularly relevant for spin relaxation in single dots at large magnetic elds and in coupled dots at weak couplings. The spin direction of a state is given by the sign of the expectation value of  $_{\rm S}^{"}$  in the direction of B .

In order to predict the spin relaxation rate in coupled dots, we rst discuss a single dot case and compare it with

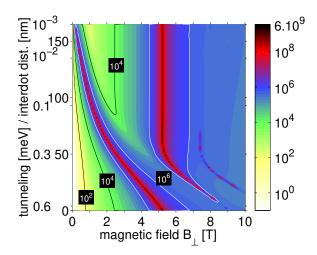


FIG. 2: (Color online) Calculated spin relaxation, in s  $^1$ , for a double quantum dot along [100] as a function of a perpendicular magnetic eld B  $_?$  and tunneling energy/interdot distance. The labeled contours are equirelaxational lines. Three spin hot spot \ridges" are visible with spin relaxation as large as  $10^9~{\rm s}^{\,1}$ . The granular pattern at spin hot spots is due to the nite resolution of the graphics.

experiment. This is shown in Fig. 1, where spin relaxation as a function of B ;; applied at di erent angles is calculated. The experim ent specic value of g = taken. Spin-orbit param eters could be adjusted from a t to the experim ental data. However, such a tispresently not possible since the calculated rates depend strongly on , re ecting the reduced sym m etry (C  $_{2v}$ ) of the G aA s interface, while the experimental data are taken for a single diagonal crystallographic direction, undetermined whether [110] or  $[\overline{110}]$  with respect to  $C_{2v}$ ) [25]. These two directions are not equivalent, which is rejected by the anisotropy shown in Fig. 1. For the purposes of dem onstration we assume ad hoc that the experiment is done for [110]; the spin-orbit param eters used in this paper are selected (the selection is by no means unique) to quantitatively describe the experiment with this [26]. This is to dem onstrate that the experim ent is consistent with the phonon-induced spin relaxation model for reasonable values of spin-orbit parameters. We disagree with the experim ent at 14 T in which cyclotron e ects (beyond the scope of our theory) in the growth direction become im portant.

The calculated anisotropy in Fig. 1 appears due to the reduced symmetry in the presence of both Bychkov-Rashba and D resselhaus terms [19]. Using a unitary transformation that eliminates the linear spin-orbit terms in a connect system [19, 27] the Zeeman term due to B  $_{\rm jj}$  transforms to an elective Zeeman term with magnetic eld B  $_{\rm z}^{\rm e}$  (x;y)2 along z:

$$B_z^e = B_{jj} \times \frac{\cos}{\frac{1}{2}B_R} \cdot \frac{\sin}{\frac{1}{2}D} + y \cdot \frac{\sin}{\frac{1}{2}B_R} \cdot \frac{\cos}{\frac{1}{2}D}$$
 :(6)

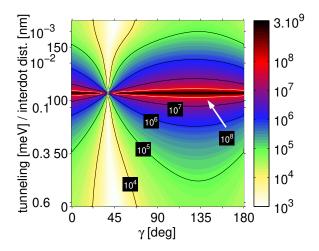


FIG .3: (Color online) Calculated spin relaxation rate, in s  $^1$ , of a double quantum dot as a function of and tunneling energy, for B  $_{\rm jj}$  = 5 T . The dots are oriented along [100]. The weakest relaxation is for 35 . Spin hot spots strongly in uence spin relaxation at tunneling energies from 0.001 to 0.1 m eV .

The spin- ip probability is proportional to the square of the transition matrix element of B $_z^e$ . Since the single dot (Fock-D arw in) upper and lower Zeem an ground states are coupled through the rst excited orbital states which can be chosen to have a denite xory symmetry, the spin relaxation rate is proportional to the sum of the squares at x and y in Eq. 6. The spin- ip probability is then proportional to the inverse of the square of the ective anisotropic spin-orbit length  $L_{\rm SO}$  ( ),

$$L_{SO}^{2}$$
 ( ) = 1= $\frac{1}{12}$  + 1= $\frac{1}{12}$  2 sin (2 )= $\frac{1}{12}$  R  $\frac{1}{12}$  : (7)

The period of relects the C  $_{2v}$  sym metry of the interface [19]. The minimum spin relaxation is at = 45, while the maximum is at 135, consistent with the numerics in Fig. 1. The anisotropy is absent if one of the spin-orbit couplings dominates. Experimental observation of such an anisotropy would be a clear signal of a phonon-induced spin relaxation and could be used to extract the ratio of  $l_{\rm b}$  and  $l_{\rm BR}$ . If  $l_{\rm BR} = l_{\rm D}$ , the anisotropy is strongest the spin relaxation rate due to the linear spin-orbit terms vanishes for = 45. Details of the analytical derivations will be published in a longer version of this article [28]. The anisotropy of Eq. 7 has been found earlier [6], while related anisotropies in g-factors has been predicted for extended two-dimensional systems [29].

We now move to double quantum dots described by the con ning potential V in Eq. 1. We have already predicted that spin hot spots in these systems appear whenever the Zeem an splitting equals the tunneling energy (dierence between symmetric and asymmetric orbital levels) [19]. At weak coupling (d  $$l_0$$ ) the Zeem an splitting dominates and spin relaxation proceeds through at least two channels, one to the symmetric ( ${}^{\rm S}_{\rm S}$ ), the other

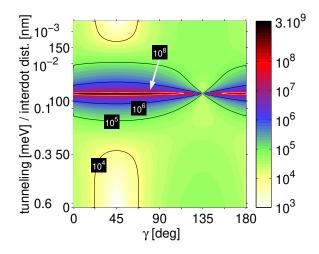


FIG. 4: (Color online) Calculated spin relaxation, in s $^1$ , of a double dot as a function of and the tunneling energy, for B $_{jj}$  = 5 T. The dots are oriented along [110]. The weakest spin relaxation is for = 135, while at = 45 spin hot spots do appear.

to the asym m etric (  $\frac{\pi}{A}$ ) orbital state. At large coupling spin relaxation is, in general, a single channel process, except at very large m agnetic elds in which Landau levels form . The two regimes are separated by a spin hot spot in which spin relaxation is as large as orbital relaxation . This regime is common typical values for the tunneling energy and the Zeem an splitting are of order 0.1 meV .

Consider rst double dots with a perpendicular magnetic eld B? which contributes both the Zeem an splitting as well as cyclotron e ects. The calculated spin relaxation as a function of tunneling energy and B? is shown in Fig. 2. The pro le is rather complex. Spin relaxation is dom inated by the presence of spin hot spots which enhance spin relaxation in most regimes of the control param eters. For tunneling energies below 02 m eV the weakest spin relaxation is for magnetic elds from 2 to 5 T.At d = 0 the calculated rate is that of single quantum dots. There is a characteristic cusp structure as a function of B? at a spin hot spot at B? 5 T (such a cusp is not seen for the in-plane eld case in Fig.1 since due to the absence of cyclotron e ects the spin-hot spots appear at large elds of B ;; 54 T). Our calculation for this single-dot case is in quantitative agreem ent with perturbative calculations[9].

Let us now look at spin relaxation in an in-plane eld B  $_{jj}$ , a situation interesting for spin qubit experiments, since cyclotron e ects are inhibited. Two important cases are shown for B  $_{jj}$  = 5 T and dierent orientations. The rst case, in which the dots are along [100], is shown in Fig. 3, and the second case, in which the dots are along [110], is shown in Fig. 4. At small and large couplings, the spin relaxation rate is strongly anisotropic, similar to the single-dot case in Fig. 1. This anisotropy is greatly enhanced in the intermediate coupling by spin hot spots.

In fact, spin hot spots dom inate this useful regime: spin relaxation is several orders of magnitude higher than in the single dot case (lim its of either very strong or very weak coupling on the graph) at virtually all . The exceptions are \$35 in Fig. 3 and \$=135 in Fig. 4. At smaller (larger) B  $_{\rm jj}$ , the strong relaxation regime m oves towards smaller (larger) coupling, while the two angles of \easy passage" remain.

The anisotropy in both  $\,$  and  $\,$  can be explained by transform ing the e ective Zeem an  $\,$  eld B  $_z^e$  , Eq. 6, into the rotated coordinate system in which the x axis lies along d:

Unlike in single dots, the relevant states in double dots are coupled by x and y di erently. At weak coupling the dominant term is the one containing x (which is the sym m etry of the rst excited orbital state  $_{A}$  [19]). This term leads to anisotropic spin hot spots and giant spin relaxation seen in Figs. 3 and 4. Spin hot spots vanish if  $l_{\rm BR}^{1} \cos($ )  $\int_{0}^{1} \sin(x+y) = 0$ , which, for x = 0, gives tan =  $\frac{1}{2}$  =  $\frac{1}{2}$  R . For our param eters the corresponding angle is about 35, consistent with the numerical calculation shown in Fig. 3. Unfortunately, this angle depends on the spin-orbit coupling and is thus not robust against m aterials and growth details. On the other hand, for = 45, the spin hot spots vanish if = 135, which is a universal value independent of spin-orbit coupling. This is con med numerically in Fig. 4. In the special case of  $l_{\!\scriptscriptstyle B\,R}\,=\,l_{\!\scriptscriptstyle D}$  , the condition for the weakest spin relaxation would be = 45, as in single dots.

In GaAs single dots spin hot spots, which appear at large magnetic elds, are due to the Bychkov-Rashba coupling only [9, 19]. On the other hand, as can be read from Eq. 8, in double dots spin hot spots appear at arbitrary small magnetic elds and are caused by both the Bychkov-Rashba and Dresselhaus couplings [19], whose interference causes spin hot spot anisotropy.

Sim ilar results apply for other growth directions. In [111]  $H_D$   $H_{B\,R}$  [20] and the above results in the lim it  $l_D$ ! 1 apply (with  $l_{B\,R}$  being a combination of both coupling strengths). The spin hot spots are inhibited for any orientation of double dots and a perpendicular inplane eld [cos( ) = 0]; such a con guration can also be used in applications. In the [110] case a unique easy passage exists for = 0 and = 90 [28].

In conclusion, we have perform ed realistic calculations of phonon-induced spin relaxation in double quantum dots in the presence of magnetic eld. The spin relaxation rate is dominated by spin hot spots in the useful regime of interdot couplings. The spin hot spot anisotropy allows an inhibited spin relaxation for the dots oriented along a diagonal of the [001] plane with a transverse in-plane magnetic eld.

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